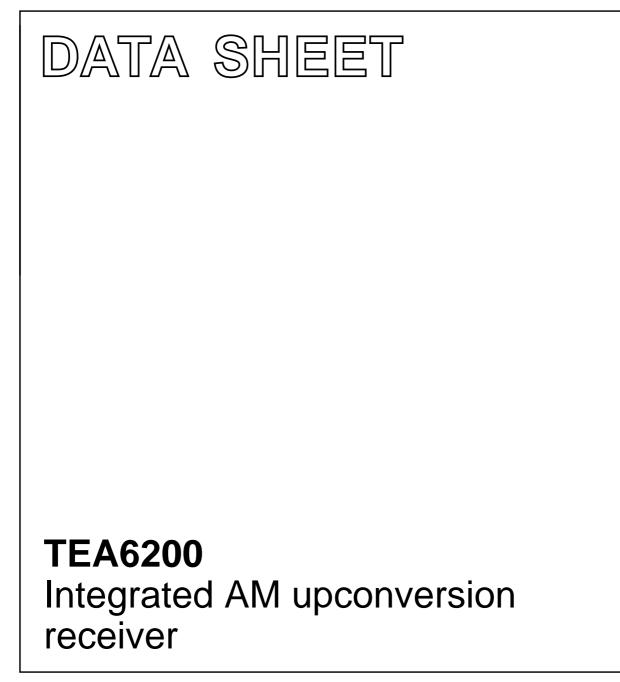
INTEGRATED CIRCUITS



Product specification File under Integrated Circuits, IC01 August 1989



HILIP

## **TEA6200**

#### **GENERAL DESCRIPTION**

The TEA6200 is an integrated AM upconversion receiver circuit with an IF of 10.7 MHz. Because of the high dynamic range of the RF prestage there is no tuned prestage. The whole selectivity is provided by crystal filters. The circuit is intended for use in AM radios with synthesizer tuning. The TEA6200 can handle RF signals up to 2 V RMS.

#### Features

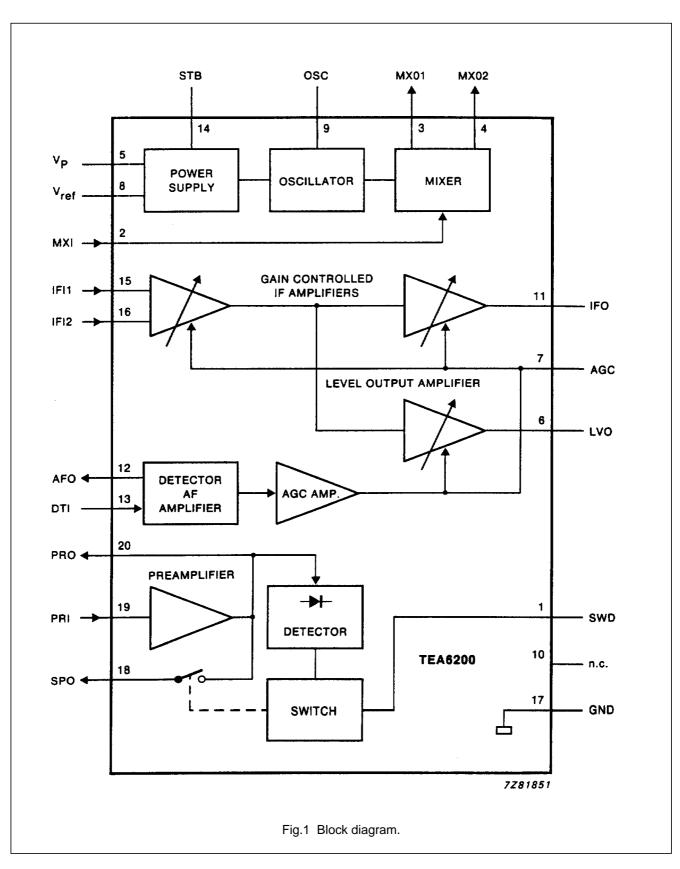
- No pre-tuned selection is required
- No LW/MW switching
- RF input is protected from static discharge from the aerial
- Electronic standby switch
- Voltage controlled oscillator for synthesizer tuning
- IF output providing level information for search tuning.
- No alignment required.

### QUICK REFERENCE DATA

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply voltage range	V <sub>P</sub>	7.6	8.5	9.4	V
Supply current range	I <sub>P</sub>	_	50	70	mA
AF output voltage with:					
RF at 1 MHz and 10 mV					
f <sub>m</sub> at 400 Hz and 30%	V <sub>af</sub>	_	350	-	mV
AGC start	V <sub>rf</sub>	30	50	80	μV
AGC range	$\Delta V_{rf}$	_	95	_	dB

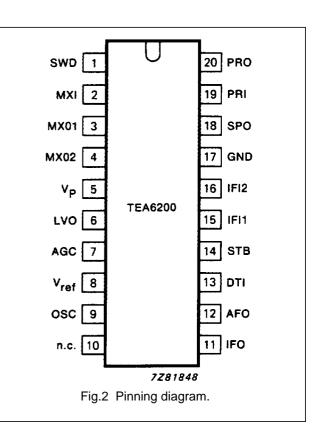
### PACKAGE OUTLINE

20-lead dual in line; plastic (SOT146); SOT146-1; 1996 August 02.



### PINNING

1	SWD	switching delay
2	MXI	mixer input
3	MXO1	mixer output 1
4	MXO2	mixer output 2
5	V <sub>P</sub>	supply voltage
6	LVO	level output
7	AGC	AGC time constant
8	V <sub>ref</sub>	reference voltage
9	OSC	oscillator
10	n.c.	not internally connected*
11	IFO	IF output
12	AFO	AF output
13	DTI	detector input
14	STB	standby switch
15	IFI1	IF input 1
16	IFI2	IF input 2
17	GND	ground
18	SPO	switched prestage output
19	PRI	prestage input
20	PRO	prestage output



\* Pin 10 must be connected to pin 5, 8 or 17.

### TEA6200

### RATINGS

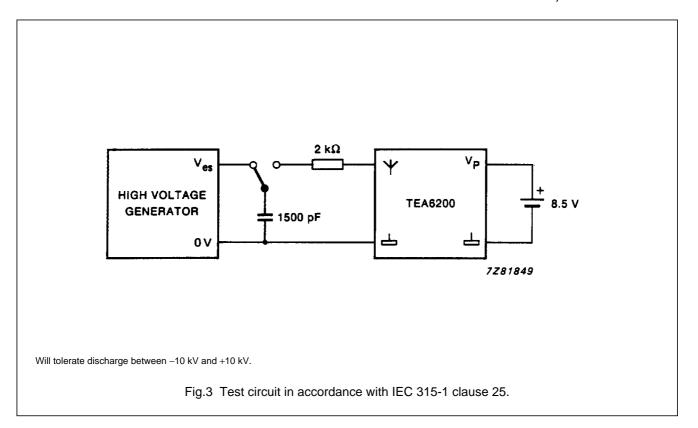
Limiting values in accordance with the Absolute Maximum System (IEC 134)

PARAMETER	SYMBOL	MIN.	MAX.	UNIT
Supply voltage	V <sub>P</sub>	_	12	V
Supply current	I <sub>P</sub>	_	70	mA
Total power dissipation	P <sub>tot</sub>	_	850	mW
Operating ambient temperature range	T <sub>amb</sub>	-30	+ 85	°C
Storage temperature range	T <sub>stg</sub>	-40	+ 150	°C
Electrostatic discharge voltage	±V <sub>es</sub>	_	10	kV

### THERMAL RESISTANCE

From junction to ambient

 $R_{th j-a} = 80 \text{ K/W}$ 



### TEA6200

### **DC CHARACTERISTICS**

 $V_P = 8.5 V$ ;  $V_{14} = V_P$ ; Signal in OFF condition; all voltages referenced to ground unless otherwise specified.

PARAMETER	CONDITIONS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Mixer input		VI	-	4.0	-	V
Mixer output 1		Vo	-	8.5	-	V
Mixer output 2		Vo	-	8.5	-	V
Level output		Vo	_	8.5	_	V
AGC voltage		V <sub>AGC</sub>	_	0.65	_	V
Reference voltage		V <sub>ref</sub>	_	4.0	_	V
Oscillator DC voltage		V <sub>OSC</sub>	_	4.0	_	V
Prestage input		VI	_	1.2	_	V
Prestage output		Vo	-	3.2	-	V

### CHARACTERISTICS

 $V_P = 8.5 \text{ V}$ ;  $T_{amb} = 25 \text{ °C}$ ;  $f_{RF} = 1 \text{ MHz}$  at 10 mV RMS;  $Q_{OSC} = 50$ ; modulation = 400 Hz at 30%; insertion loss of filters: crystal filter = 1 dB; ceramic filter = 4 dB, all voltages referenced to ground unless otherwise specified.

PARAMETER	CONDITIONS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply						
Supply voltage range		V <sub>P</sub>	7.6	8.5	9.4	V
Supply current range		I <sub>P</sub>	-	50	70	mA
Guaranteed operating voltage		V <sub>P</sub>	7.0	-	10.0	V
Standby switch						
ON voltage		V <sub>14</sub>	3.2	-	V <sub>P</sub>	V
OFF voltage		V <sub>14</sub>	0	-	1	V
ON current		I <sub>14</sub>	-	-	10	μΑ
OFF current		-l <sub>14</sub>	-	-	0.5	mA
Supply current	device OFF	I <sub>P</sub>	-	-	10	mA
Prestage	note 1					
Switching threshold	modulation					
	= 80%	V <sub>rf</sub>	-	320	-	mV
Hysteresis		V <sub>rf</sub>	1.5	3.5	5.5	dB
Oscillator						
Frequency range		f <sub>osc</sub>	10.8	_	17.8	MHz
Oscillator amplitude		V <sub>osc</sub>	200	420	_	mV
Tuned circuit selectivity		Q <sub>OSC</sub>	20	50	-	-
Mixer						
Input capacitance		C <sub>2-8</sub>	_	5	10	pF
Input impedance		Z <sub>2-8</sub>	10	40	-	kΩ
Conversion transconductance		I <sub>3-4</sub> /V <sub>2-8</sub>	-	3.8	-	S

PARAMETER	CONDITIONS	SYMBOL	MIN.	TYP.	MAX.	UNIT
IF amplifier						
Input impedance		R <sub>16-15</sub>	10	_	_	kΩ
Input capacitance		C <sub>16-15</sub>	-	_	5	pF
Output impedance		Z <sub>11</sub>	230	330	430	Ω
Detector	note 2					
Input impedance		Z <sub>13</sub>	265	380	500	Ω
Output impedance		Z <sub>12</sub>	7	10	14	kΩ
Output level		V <sub>af</sub>	250	350	500	mV
Reference voltage						
Voltage	V <sub>P</sub> = 8.5 V	V <sub>8</sub>	3.8	4.0	4.2	V
Output impedance		Z <sub>8</sub>	-	20	_	Ω
Ripple rejection		$rac{\Delta V_P}{\Delta V_8}$	40	-	-	dB
Level output pin 6	see Fig.5					
Output impedance		Z <sub>6</sub>	_	1	_	kΩ
Output voltage	V <sub>rf</sub> = 70 μV	V <sub>6</sub>	0.5	0.7	1.0	mV
Output voltage	$V_{rf} = 2 \text{ mV}$	V <sub>6</sub>	_	15	_	mV
RF sensitivity						
RF input	(S + N)/N = 6 dB	V <sub>rf</sub>	_	11	20	μV
	(S + N)/N = 26  dB	V <sub>rf</sub>	_	110	150	μV
	(S + N)/N = 46  dB	V <sub>rf</sub>	-	1100	2000	μV
	RF = 150 kHz					
	(S + N)/N = 26  dB	V <sub>rf</sub>	-	200	_	μV
Output signal						
AF output voltage	$V_{rf} = 10 \text{ mV}$	V <sub>af</sub>	250	350	500	mV
	$V_{rf} = 20 \ \mu V$	V <sub>af</sub>	-	100	-	mV
Total distortion	$V_{rf} = 1 \text{ mV};$					
	modulation = 80%	d <sub>tot</sub>	-	3	5	%
Signal plus noise-to-noise ratio	RF = 10 mV to 1 V	(S + N)/N	53	57	-	dB
Ripple rejection	$V_{P} = 8.5 V + V_{r}$					
	20 Hz < fR < 20 kHz	$\Delta V_P$	20	_	_	dB
	$V_{rms} = 40 \text{ mV}$	$\overline{\Delta V_{af}}$				

### TEA6200

PARAMETER	CONDITIONS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Large signal handling						
Aerial input voltage	THD = 10%;					
	modulation = 80%	V <sub>rf</sub>	2	3	_	V
AGC range of preamplifier switch			_	12	-	dB
Switching threshold	modulation = 80%	V <sub>rf</sub>	_	320	_	mV
Hysteresis	modulation = 80%	V <sub>rf</sub>	1.5	3.5	5.5	dB
Ripple rejection of preamplifier	20 Hz < f <sub>R</sub> < 1.5 MHz	$\frac{\Delta V_{P}}{\Delta V}$	_	40	-	dB
AGC		$\overline{\Delta V_{20}}$				
AGC range			_	95	_	dB
Change of V <sub>af</sub>	100 μV < V <sub>rf</sub> < 2 V		_	2	3	dB
AGC start		V <sub>rf</sub>	30	50	80	μV
Intermodulation free dynamic range						
Long wave	350/250 kHz					
second order	input noise level					
	= -99 dBm	I MFDR 2	72	82	-	dB
third order	input noise level					
	= –99 dBm	I MFDR 3	-	86	-	dB
Medium wave	650/1550 kHz					
second order	input noise level					
	= -104 dBm	I MFDR 2	74	84	-	dB
third order	1.25/1.4 MHz					
	input noise level					
	= -104 dBm	I MFDR 3	-	90	-	dB

#### Notes to the characteristics

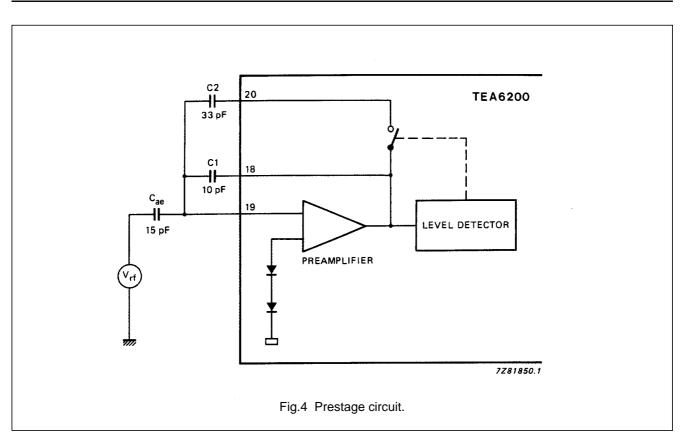
 The prestage is connected to the aerial by a 6 MHz low-pass filter that decouples unwanted aerial cable resonance frequencies. The large dynamic range of the prestage is achieved by use of a transimpedance amplifier with a feedback loop consisting of an equivalent aerial capacitance and a feedback capacitor. When large RF signals are received the feedback capacitance in the loop is increased and the gain subsequently reduced, (see Fig.4).

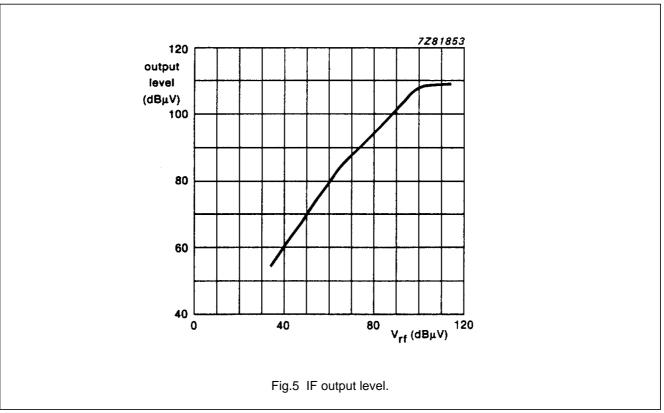
Voltage gain for small signals

$$G_{V} = V_{rf} \times \frac{C_{ae}}{C_{1}}$$
$$G_{V} = V_{rf} \times \frac{C_{ae}}{C_{1} + C_{2}}$$

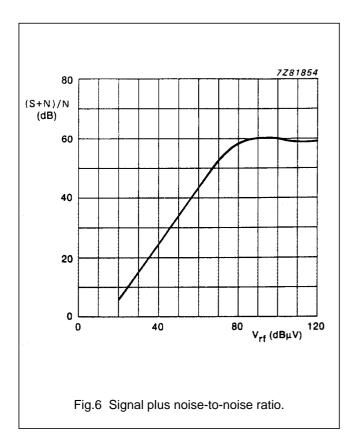
Voltage gain for large signals

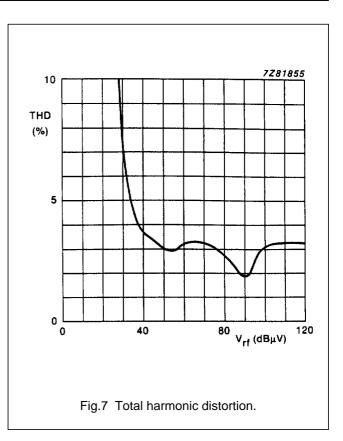
2. To protect the demodulator and the AGC circuitry, against parasitic oscillation in the IF section, a ceramic filter is connected between the IF output and detector input.





# TEA6200





### **APPLICATION INFORMATION**

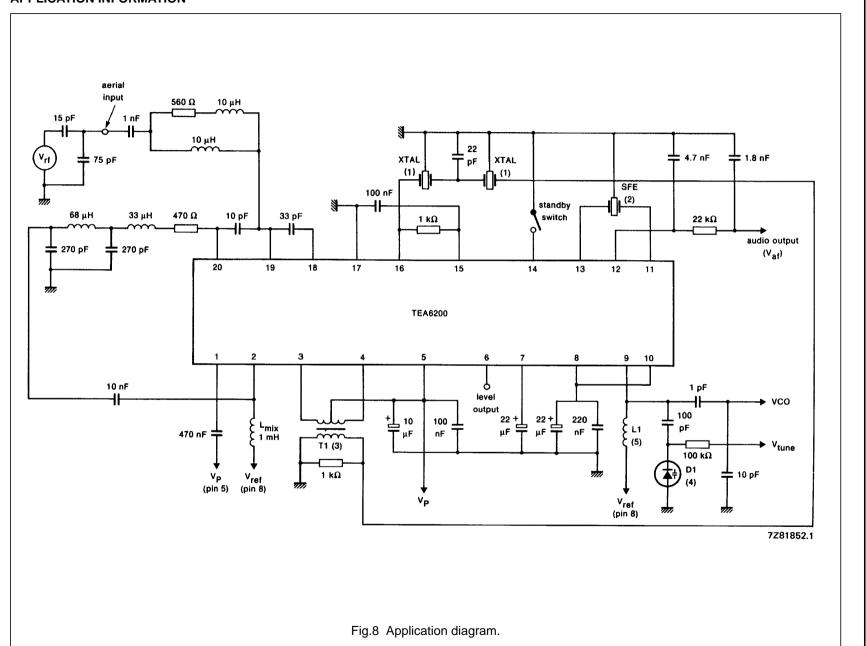
### Notes Fig. 8.

	COMPONENT	CIRCUIT IDENTITY	SUPPLIER REFERENCE
(1)	Crystal filters	XTAL	NDK 10T 7 BA
(2)	Ceramic filter	SFE	Murata E 10 7 S
(3)	Transformer	T1	Toko 7PS-1078 JK
(4)	Variable capacitance diode.	D1	BB609, BB809 or BBY40
(5)	Oscillator coil	L1	Toko 7PS-1077 X

**APPLICATION INFORMATION** 

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August 1989



Philips Semiconductors

Integrated AM upconversion receiver

1

Product specification

OUTLINE

VERSION

SOT146-1

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

IEC

EIAJ

SC603

EUROPEAN PROJECTION

ISSUE DATE

<del>92-11-17</del>

95-05-24

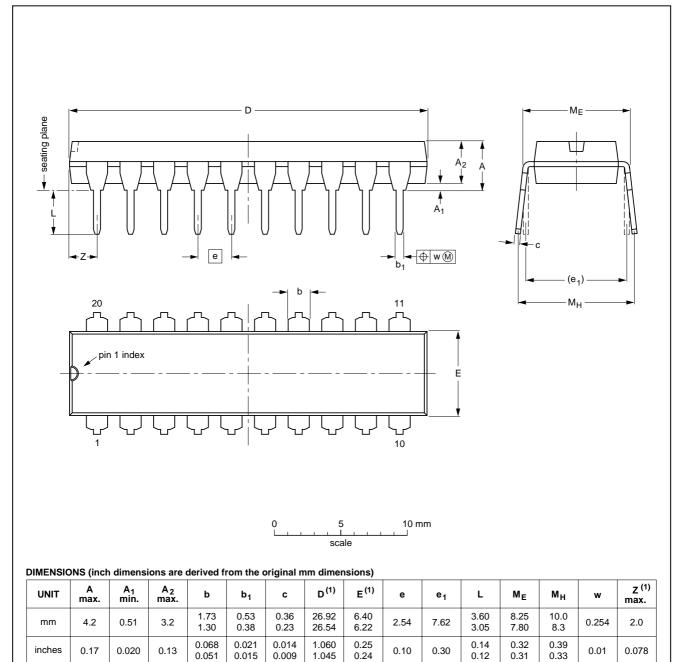
REFERENCES

JEDEC

## Integrated AM upconversion receiver

### PACKAGE OUTLINE

DIP20: plastic dual in-line package; 20 leads (300 mil)



# TEA6200

SOT146-1

## TEA6200

### SOLDERING

#### Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"IC Package Databook"* (order code 9398 652 90011).

#### Soldering by dipping or by wave

The maximum permissible temperature of the solder is 260 °C; solder at this temperature must not be in contact with the joint for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified maximum storage temperature ( $T_{stg max}$ ). If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

#### **Repairing soldered joints**

Apply a low voltage soldering iron (less than 24 V) to the lead(s) of the package, below the seating plane or not more than 2 mm above it. If the temperature of the soldering iron bit is less than 300 °C it may remain in contact for up to 10 seconds. If the bit temperature is between 300 and 400 °C, contact may be up to 5 seconds.

### DEFINITIONS

Data sheet status					
Objective specification	bjective specification This data sheet contains target or goal specifications for product development.				
Preliminary specification	cification This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	n This data sheet contains final product specifications.				
Limiting values					
more of the limiting values of the device at these or at	Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.				
Application information					
Where application information is given, it is advisory and does not form part of the specification.					

### LIFE SUPPORT APPLICATIONS

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